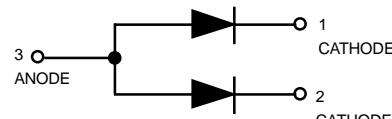
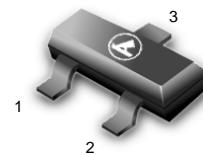


Monolithic Dual Switching Diode

Common Anode


BAW56LT1

CASE 318-08, STYLE12
SOT- 23 (TO-236AB)

MAXIMUM RATINGS (EACH DIODE)

| Rating | Symbol | Value | Unit |
|----------------------------|-----------------|-------|------|
| Reverse Voltage | V_R | 70 | Vdc |
| Forward Current | I_F | 200 | mAdc |
| Peak Forward Surge Current | $I_{FM(surge)}$ | 500 | mAdc |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------------|-------------|---------------------------|
| Total Device Dissipation FR- 5 Board (1) | P_D | 225 | mW |
| $T_A = 25^\circ\text{C}$ | | | |
| Derate above 25°C | | 1.8 | mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient | R_{JJA} | 556 | $^\circ\text{C}/\text{W}$ |
| Total Device Dissipation | P_D | 300 | mW |
| Alumina Substrate, (2) $T_A = 25^\circ\text{C}$ | | | |
| Derate above 25°C | | 2.4 | mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction to Ambient | R_{JJA} | 417 | $^\circ\text{C}/\text{W}$ |
| Junction and Storage Temperature | T_J, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

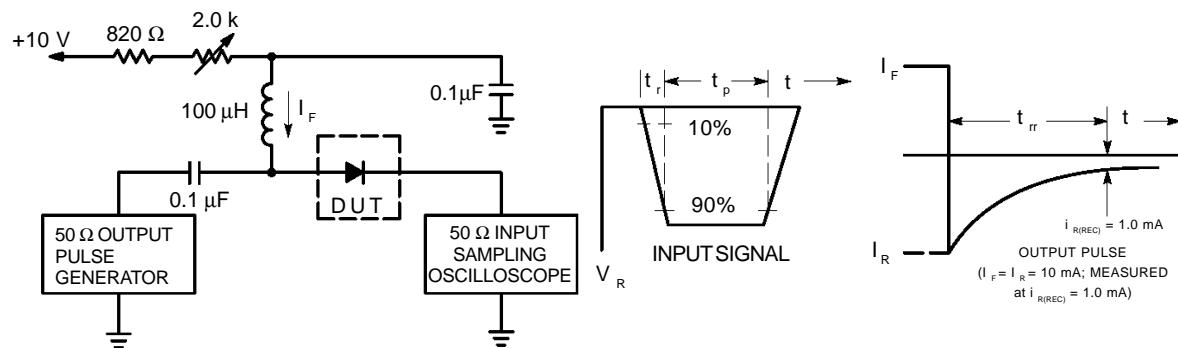
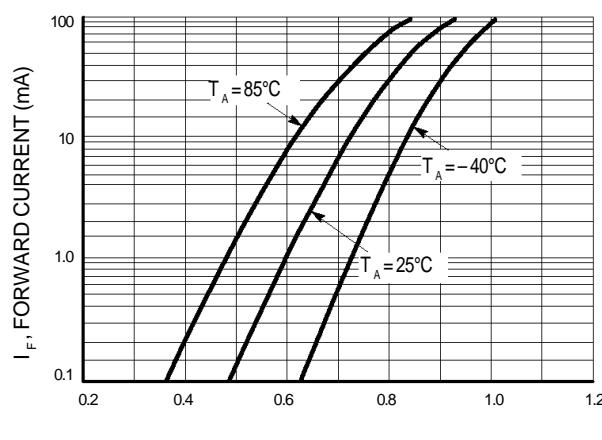
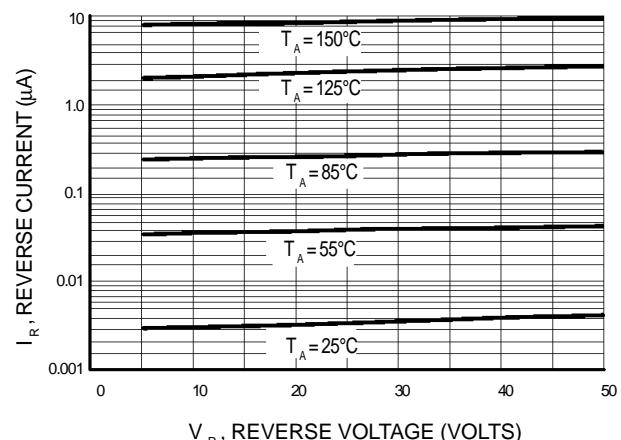
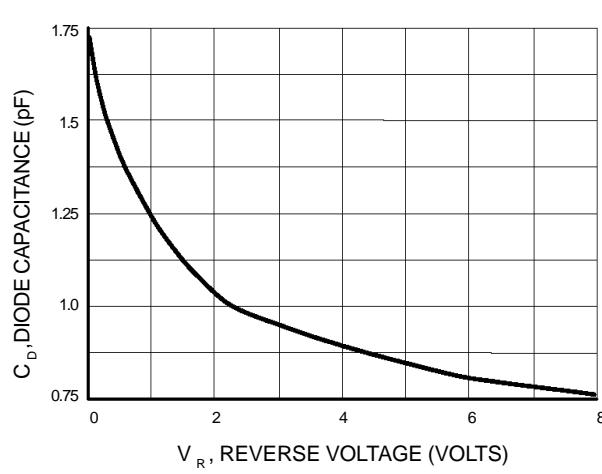
DEVICE MARKING

BAW56LT1 = A1

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (EACH DIODE)

| Characteristic | Symbol | Min | Max | Unit |
|---|------------|-----|----------------------------|-----------------|
| OFF CHARACTERISTICS | | | | |
| Reverse Breakdown Voltage ($I_{(BR)} = 100 \mu\text{Adc}$) | $V_{(BR)}$ | 70 | — | Vdc |
| Reverse Voltage Leakage Current ($V_R = 25 \text{ Vdc}, T_J = 150^\circ\text{C}$) ($V_R = 70 \text{ Vdc}$) ($V_R = 70 \text{ Vdc}, T_J = 150^\circ\text{C}$) | I_R | — | 30 2.5 50 | μAdc |
| Diode Capacitance ($V_R = 0, f = 1.0 \text{ MHz}$) | C_D | — | 2.0 | pF |
| Forward Voltage ($I_F = 1.0 \text{ mAdc}$) ($I_F = 10 \text{ mAdc}$) ($I_F = 50 \text{ mAdc}$) ($I_F = 150 \text{ mAdc}$) | V_F | — | 715 855 1000 1250 | mVdc |
| Reverse Recovery Time ($I_F = I_R = 10 \text{ mAdc}, I_{R(\text{REC})} = 1.0 \text{ mAdc}$) (Figure 1) $R_L = 100\Omega$ | t_{rr} | — | 6.0 | ns |

1. FR-5 = $1.0 \times 0.75 \times 0.062 \text{ in.}$ 2. Alumina = $0.4 \times 0.3 \times 0.024 \text{ in. } 99.5\% \text{ alumina.}$

BAW56LT1

Figure 1. Recovery Time Equivalent Test Circuit
CURVES APPLICABLE TO EACH CATHODE

Figure 2. Forward Voltage

Figure 3. Leakage Current

Figure 4. Capacitance